Comparison and Analysis of Electronic Voltage Transformer Based on Voltage Detection

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ABSTRACT The electronic voltage Transformer (EVT) constitutes key equipment in the intelligent substation; during the half-a-century development, numerous categories have emerged. By analysis and comparison of the working mechanisms and features of various electronic voltage transformers, we have concluded the strengths and defects in various mechanisms and impact factors on the features of voltage transformer and raised specific measures to reduce the impact and problems found in the design. The findings have revealed that ECVT is the mainstream product in the electronic voltage transformer market but interim measuring accuracy requires for improvement; ERVT is limited by the resistance power and insulating property, and not applicable to the higher voltage level; OVT assures excellent measuring quality in the sensing mechanism. However, the application progress will be slowed down due to several factors: the complex production process, measuring precision easily affected by light power fluctuation and temperature change and transmission by optical fibers with a little effect in simplifying insulation and trimming cost.

KEYWORDS Voltage transformer ECVT ERVT Voltage detection OVT

1. Introduction
The electronic voltage transformer includes two categories in the detection mechanism: detection voltage type and detection current type. The detection voltage type EVT includes the electronic capacitance voltage transformer (ECVT), electronic resistance voltage transformer (ERVT) and optical voltage transformer (OVT): They refer to Pockels electro-optic effect type OVT and inverse piezoelectric effect type OVT. This paper makes comparison and analysis on the mechanisms and features of said electronic voltage transformers, concludes the strengths and defects of various mechanisms and impact factors on voltage transformer features, and raises notices in the design and measures adopted to reduce impact.

2. General structure of electronic voltage transformer
According to the standard definition of IEC, the general structure of electronic voltage transformer is composed of primary part, secondary part and transmission system as shown in Figure 1, P1, P2 refer to primary input ends; according to different detection mechanisms, they can be voltage input or current input [1]. The transmission system is collocated with cable or optical cable; in the digital substation, optical fiber is an ideal choice. The secondary output of analog volume is S1, S2 in order to connect with the traditional metering or protective unit.

According to the primary sensing mechanisms and different combinations of transmission system, EVT general structure’s primary component can be neglected in some areas while various procedures of secondary part are not affected. Take optical voltage transformer as an example, since the optical fiber transmission can directly transmit optical measuring signal, primary converter is not needed,
while primary power supply is not needed either. With constant deepening of secondary equipment digitalization, the analog interface of secondary converter is gradually cancelled.

3. Detection voltage type electronic voltage transformer

3.1. ECVT

The ECVT adopts capacitor as the sensor; in spite of slight differences of sensors in the structure (designed by different manufacturers) [2–7], ECVT mechanism and structure are described in Figure 2; the figure neglects the power supply of high/low-voltage side electronic parts.

Figure 2. ECVT mechanism and structure.

In the said sensor in the figure, the secondary divided voltage procedure adopts resistance or capacitance. If the power supply is connected at the capacitance C2 side of low-voltage arm in a parallel manner and resistance R is 1/ \( R \omega (C1+C2) \) (\( \omega \)—angle frequency of measured voltage), the sensor outputs the differential of measured signal. In the micro-computer treatment, the digital credit is reduced and measured.

ECVT integrates the strengths of capacitance voltage transformer (CVT) and OVT. It is deemed as the mainstream product of EVT. However, it has the following defects:

1) The measuring accuracy is affected by the sundry capacitance and capacitance temperature factor; in the design, capacitance with low temperature factor is selected and adopted, and shield hood is installed in the high-voltage part of transformer to remove or reduce negative impacts of sundry capacitance.

2) ECVT suffers from interim measuring errors: It mainly includes catching of power load and short circuit at the outlet of high-voltage side. Take catching of power load as an example, if the line is switched off, the power load of line equivalent capacitance C may be caught by ECVT capacitance voltage divider as shown in Figure 3. The catching volume of power load depends on the instantaneous voltage in the switch-off. C2 is connected with equivalent parallel resistance R of connected equipment to discharge power; power load Q stored in C1 is difficult to discharge; if the line is connected for the second time, the line immediately discharges power through low DC impedance of power grid. As a result, power load of C1 is transferred to C2 and C2 is charged to the output value of secondary voltage. It is attenuated according to the time constant RC2; larger R leads to slower attenuation and longer error time.

3) ECVT may suffer from high EVT secondary voltage [8] in the switch-on of isolating switch; the reason lies in too large equivalent parallel resistances of low-voltage arm, accumulation of residual capacitance load and difficulty in discharge. Therefore, special attention is paid to the equivalent parallel resistance of low-voltage arm in ECVT design.

3.2. ERVT

The ERVT differs from the ECVT mainly in the sensor; the precise resistance voltage divider is collocated as the sensing component [9]. The sensing component is featured as mature technology and high measuring accuracy; however, it is limited by the resistance power and insulating property and mainly applicable to medium/low-voltage distribution fields such as 10 kV and 35 kV. Figure 4 demonstrates the mechanism and structure of ERVT sensor.

Figure 3. ECVT catching of power load.

Figure 4. Mechanism and structure of ERVT sensor.

The resistance voltage divider includes the high-voltage arm resistance R1, low-voltage arm resistance R2 and over-voltage protective gas discharge pipe S. The measuring quality is mainly affected by the resistance features and sundry capacitance. Highly stably thick film resistance is collocated for 10 kV and 25 kV voltages as the high/low-voltage arm resistance of voltage divider. In order to block the negative impacts of sundry capacitance, the shield hood is installed to improve the distribution of electric field of voltage divider (same as ECVT).

3.3. Optical voltage transformer

In the respect of mechanism, the optical voltage transformer includes OVT based on Pockels electro-optical effect and OVT based on inverter effect. However, both of them make use of the optical crystal and reflect the changed physical volume of electric field strength and thus calculate
the electric field strength and voltage. Take Pockels electro-optical effect as an example, if the light passes through the electro-optical crystal under the external electric field, double reflection is produced; the phase difference of double reflected light waves is in proportion to the strength of electric field; if the electric field has a fixed distance from the crystal, voltage in the crystal is in proportion. The inverter effect refers to the following condition: If the voltage crystal is affected by the external electric field, it will have certain changes and transfer into the modulation of light signal and inspect the light signal; therefore, it can realize the optical sensing of electric field (or voltage). Figure 5 and Figure 6 demonstrate the mechanism and structure of two OVT sensors.

4. Conclusion
The paper discusses about the electronic voltage transformer in various mechanisms and draws the following conclusions:
(1) Currently, ECVT is the mainstream product of electronic voltage transformer; however, the interim measuring accuracy needs improvement.
(2) ERVT is limited by the resistance power and insulating property and not applicable to the higher voltage level.
(3) OVT assures excellent measuring quality in the sensing mechanism; however, the application progress will be slowed down due to several factors: the complex production process, measuring precision easily affected by light power fluctuation and temperature change and transmission by optical fibers with a little effect in simplifying insulation and trimming cost.

Conflicts of interest
These authors have no conflicts of interest to declare.

Author’s contributions
These authors contributed equally to this work.

References